() IDT.

DATASHEET

6-OUTPUT LOW-POWER HCSL BUFFER FOR PCIE GEN1-2-3 AND QPI

9ZXL0651

General Description

The 9ZXL0651 is a low-power 6-output differential buffer that meets all the performance requirements of the Intel DB1200Z specification. It consumes 50% less power than standard HCSL devices and has internal terminations to allow direct connection to 85 ohm transmission lines. The 9ZXL0651 is backwards compatible to PCIe Gen1 and Gen2 and QPI 6.4GT/s specifications. A fixed, internal feedback path maintains low drift for critical QPI applications.

Recommended Application

6-Output Low-Power HCSL Buffer for PCIe Gen1-2-3 and QPI

Output Features

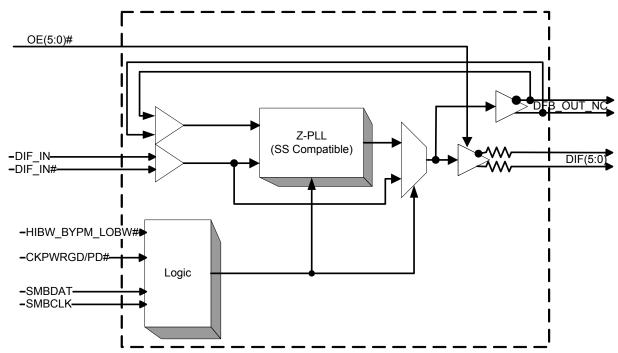
 6 - 0.7V low-power HCSL (LP-HCSL) output pairs w/integrated terminations

Features/Benefits

- Low-Power-HCSL outputs w/Zo = 85Ω; save power and board space - no termination resistors required. Ideal for blade servers.
- Space-saving 40-pin VFQFPN package
- Fixed feedback path for 0ps input-to-output delay
- 6 OE# pins; Hardware control of each output
- PLL or bypass mode; PLL can dejitter incoming clock
- Selectable PLL bandwidth; minimizes jitter peaking in downstream PLL's
- Spread Spectrum Compatible; tracks spreading input clock for low EMI

Key Specifications

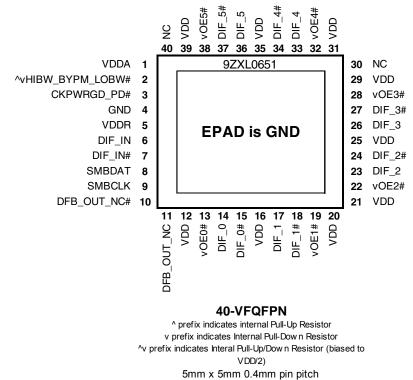
- Cycle-to-cycle jitter <50ps
- Output-to-output skew <65 ps
- Input-to-output delay variation <50ps
- PCIe Gen3 phase jitter <1.0ps RMS
- QPI 9.6GT/s 12UI phase jitter <0.2ps RMS



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Block Diagram

Pin Configuration



Power Management Table

CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit	DIF(5:0)/ DIF(5:0)#	PLL STATE IF NOT IN BYPASS MODE
0	Х	Х	Low/Low	OFF
4	Dunning	0	Low/Low	ON
I	Running	1	Running	ON

PLL Operating Mode

HiBW_BypM_LoBW#	MODE	
Low	PLL Lo BW	
Mid	Bypass	
High	PLL Hi BW	
	Bypass	

NOTE: PLL is OFF in Bypass Mode

Power Connections

Pin N	umber	
VDD	GND	Description
1	41	Analog PLL
5	4	Analog Input
12,16,20,24,27	44	DIE alaaka
,31,32,36,40	41	DIF clocks

PLL Operating Mode Readback Table

HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6
Low (Low BW)	0	0
Mid (Bypass)	0	1
High (High BW)	1	1

Tri-level Input Thresholds

Level	Voltage
Low	<0.8V
Mid	1.2 <vin<1.8v< td=""></vin<1.8v<>
High	Vin > 2.2V

9ZXL0651 SMBus Address

1101100	+ Read/Write bit

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9ZXL0651

Pin Descriptions

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
1	VDDA		3.3V power for the PLL core.
2	^vHIBW_BYPM_LOBW#	LATCHE D IN	Trilevel input to select High BW, Bypass or Low BW mode. See PLL Operating Mode Table for Details.
3	CKPWRGD_PD#	Trays	3.3V Input notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on subsequent assertions. Low enters Power Down Mode.
4	GND	GND	Ground pin.
5	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
6	DIF_IN	IN	0.7 V Differential True input
7	DIF_IN#	IN	0.7 V Differential Complementary Input
8	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
9	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
10	DFB_OUT_NC#	OUT	Complementary half of differential feedback output, provides feedback signal to the PLL for synchronization with input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal to the package.
11	DFB_OUT_NC	OUT	True half of differential feedback output, provides feedback signal to the PLL for synchronization with the input clock to eliminate phase error. This pin should NOT be connected on the circuit board, the feedback is internal to the package.
12	VDD	PWR	Power supply, nominal 3.3V
13	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
14	DIF_0	OUT	0.7V differential true clock output
15	DIF_0#	OUT	0.7V differential Complementary clock output
16	VDD	PWR	Power supply, nominal 3.3V
17	DIF_1	OUT	0.7V differential true clock output
18	DIF_1#	OUT	0.7V differential Complementary clock output
19	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
20	VDD	PWR	Power supply, nominal 3.3V
21	VDD	PWR	Power supply, nominal 3.3V
22	vOE2#	IN	Active low input for enabling DIF pair 2. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
23	DIF_2	OUT	0.7V differential true clock output
24	DIF_2#	OUT	0.7V differential Complementary clock output
25	VDD	PWR	Power supply, nominal 3.3V
	DIF_3	OUT	0.7V differential true clock output
27	DIF_3#	OUT	0.7V differential Complementary clock output
28	vOE3#	IN	Active low input for enabling DIF pair 3. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
29	VDD	PWR	Power supply, nominal 3.3V
30	NC	N/A	No Connection.
31	VDD	PWR	Power supply, nominal 3.3V
32	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
33	DIF_4	OUT	0.7V differential true clock output
34	DIF_4#	OUT	0.7V differential Complementary clock output
35	VDD	PWR	Power supply, nominal 3.3V
36	DIF_5	OUT	0.7V differential true clock output
37	DIF_5#	OUT	0.7V differential Complementary clock output
38	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
39	VDD	PWR	Power supply, nominal 3.3V
40	NC	N/A	No Connection.
41	EPAD	GND	Ground Pad.

IDT® 6-OUTPUT LOW-POWER HCSL BUFFER FOR PCIE GEN1-2-3 AND QPI

9ZXL0651

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Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9ZXL0651. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	VDD, VDDA,						
3.3V Core Supply Voltage	VDDR	VDD for core logic and PLL			4.6	V	1,2
Input Low Voltage	V _{IL}		GND-0.5			V	1
Input High Voltage	V _{IH}	Except for SMBus interface			V_{DD} +0.5V	V	1
Input High Voltage	VIHSMB	SMBus clock and data pins			5.5V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

Electrical Characteristics–Clock Input Parameters

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 V + -5\%$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input High Voltage - DIF_IN	VIHDIF	Differential inputs (single-ended measurement)	600	800	1150	mV	1
Input Low Voltage - DIF_IN	VILDIF	Differential inputs (single-ended measurement)	V _{SS} - 300	0	300	mV	1
Input Common Mode Voltage - DIF_IN	V _{COM}	Common Mode Input Voltage	300		1000	mV	1
Input Amplitude - DIF_IN	V _{SWING}	Peak to Peak value (single-ended measurement)	300		1450	mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.35			V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA	1
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45	50	55	%	1
Input Jitter - Cycle to Cycle	J _{DIFIn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

²Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics–Input/Supply/Common Parameters

$T_A = T_{COM};$	Supply	Voltane	$V_{} - 3$	2 3 V	±/-5%
$I_A = I_{COM}$	Supply	vollage	$v_{DD} = 3$	5.3 V	+/-0 %

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating Temperature	T _{COM}	Commmercial range	0	35	70	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V _{DD} + 0.3	V	1
Input Low Voltage	VIL	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	V	1
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	1
Input Current	I _{INP}	Single-ended inputs $V_{IN} = 0 V$; Inputs with internal pull-up resistors $V_{IN} = VDD$; Inputs with internal pull-down resistors	-200		200	uA	1
land Francisco	F _{ibyp}	V _{DD} = 3.3 V, Bypass mode	1		150	MHz	2
Input Frequency	F _{ipll}	V _{DD} = 3.3 V, 100MHz PLL mode	90	100.00	110	MHz	2
Pin Inductance	L _{pin}				7	nH	1
	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C_{INDIF_IN}	DIF_IN differential clock inputs	1.5		70 °C 70 °C VDD + 0.3 V 0.8 V 5 uA 200 uA 150 MHz 110 MHz 150 MHz 110 MHz 130 MHz 33 kHz 12 cycle 300 us 10 ns 0.8 V VDDSMB V 0.4 V 5.5 V 1000 ns 300 ns 0.4 V	pF	1,4
	C _{OUT}	Output pin capacitance			6	°C V UA UA UA MHz MHz MHz nH pF pF pF ms kHz cycles us kHz cycles Us NS V V V V V N NA	1
Clk Stabilization	T _{STAB}	From V _{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.53	1	ms	1,2
Input SS Modulation Frequency	f _{MODIN}	Allowable Frequency (Triangular Modulation)	30		33	kHz	1
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	4	8	12	cycles	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of control inputs			10	ns	1,2
Trise	t _R	Rise time of control inputs			10	ns	1,2
SMBus Input Low Voltage	VILSMB				0.8	V	1
SMBus Input High Voltage	VIHSMB		2.1		V _{DDSMB}	V	1
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4	V	1
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	1
Nominal Bus Voltage	V _{DDSMB}	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			100	kHz	1,5

¹Guaranteed by design and characterization, not 100% tested in production.

 $^2\mbox{Control}$ input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴DIF IN input

⁵The differential input clock must be running for the SMBus to be active

Electrical Characteristics–DIF 0.7V Low Power HCSL Outputs

$T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 \text{ V} + -5\%$									
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES		
Slew rate	Trf	Scope averaging on	1	2.9	4	V/ns	1, 2, 3		
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		7	20	%	1, 2, 4		
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	754	850	mV	1		
Voltage Low	VLow	averaging on)		62	150		1		
Max Voltage	Vmax	Measurement on single ended signal using		827	1150	mV	1		
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	10		mv	1		
Vswing	Vswing	Scope averaging off	300	1395		mV	1, 2		
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	300	453	550	mV	1, 5		
Crossing Voltage (var)	∆-Vcross	Scope averaging off		14	140	mV	1, 6		

¹Guaranteed by design and characterization, not 100% tested in production. $C_{L} = 2pF$, $Zo = 85\Omega$ differential trace impedance).

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

Electrical Characteristics–Current Consumption

Г _А = Т _{СОМ} ; Supply Voltage V	/ _{DD} = 3.3 V +/-{	5%					
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	I _{DDVDDR}	100MHz, VDDR rail		4	6	mA	1
Operating Current	I _{DDVDDAPLL}	100MHz, VDDA rail, PLL Mode		14	20	mA	1
Operating Current	I _{DDVDDABYP}	100MHz, VDDA rail, Bypass Mode		3	5	mA	1
	IDDVDD	100MHz, VDD rail		41	50	mA	1
	IDDVDDRPD	Power Down, VDDR Rail		3.5	5	mA	1
Powerdown Current	I _{DDVDDAPD}	Power Down, VDDA Rail		1.6	3	mA	1
	IDDVDDPD	Power Down, VDD Rail		0.3	2	mA	1

¹Guaranteed by design and characterization, not 100% tested in production.

 ${}^{2}C_{1} = 2pF$, Zo = 85 Ω differential trace impedance

Electrical Characteristics–Skew and Differential Jitter Parameters

$T_A = T_{COM};$	Supply	Voltage	Vpp -	33V	+/-5%
IA - ICOM	Suppry	vollage	v DD −	0.0 V	+/-J/0

	1			-		1	
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t _{SPO_PLL}	In-to-Out Skew in PLL mode @ 100MHz nominal value @35°C, 3.3V	-100	53	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t _{PD_BYP}	In-to-Out Skew in Bypass mode @ 100MHz nominal value @ 35°C, 3.3V	2.5	3.4	4.5	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSPO_PLL}	In-to-Out Skew Varation in PLL mode across voltage and temperature	-50	0	50	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSPO_BYP}	In-to-Out Skew Varation in Bypass mode across voltage and temperature	-250	0	250	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DTE}	Random Differential Tracking error beween two 9ZX devices in Hi BW Mode		3	5	ps (rms)	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSSTE}	Random Differential Spread Spectrum Tracking error beween two 9ZX devices in Hi BW Mode		15	75	ps	1,2,3,5,8
DIF{x:0]	t _{SKEW_ALL}	Output-to-Output Skew across all outputs (Common to Bypass and PLL mode)		39	65	ps	1,2,3,8
PLL Jitter Peaking	j _{peak-hibw}	LOBW#_BYPASS_HIBW = 1			2.5	dB	7,8
PLL Jitter Peaking	j _{peak-lobw}	LOBW#_BYPASS_HIBW = 0			2	dB	7,8
PLL Bandwidth	pll _{HBW}	LOBW#_BYPASS_HIBW = 1			4	MHz	8,9
PLL Bandwidth	pll _{LOBW}	LOBW#_BYPASS_HIBW = 0			1.4	MHz	8,9
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50.1	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode @100MHz		-1.7	121	%	1,10
Jitter, Cycle to cycle	t.	PLL mode		14	50	ps	1,11
	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		0	25	ps	1,11

Notes for preceding table:

¹ $C_L = 2pF$, $Zo = 85\Omega$ differential trace impedance. Input to output skew is measured at the first output edge following the corresponding input.

² Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

³ All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

⁴ This parameter is deterministic for a given device

⁵ Measured with scope averaging on to find mean value.

⁶.t is the period of the input clock

⁷ Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

^{8.} Guaranteed by design and characterization, not 100% tested in production.

⁹ Measured at 3 db down or half power point.

¹⁰ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

¹¹ Measured from differential waveform

Electrical Characteristics–Phase Jitter Parameters

 $T_A = T_{COM}$; Supply Voltage $V_{DD} = 3.3 V + -5\%$

						INDUSTRY		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMIT	UNITS	Notes
	t _{jphPCleG1}	PCIe Gen 1		43	46	86	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.4	1.5	3	ps (rms)	1,2
	t _{jphPCleG2}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.4	2.7	3.1	ps (rms)	1,2
	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)		0.56	0.61	1	ps (rms)	1,2,4
Phase Jitter, PLL Mode		QPI & SMI (PLL BW of 17.04MHz 100/133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.27	0.51	1	ps (rms)	1,5
	t _{jphQPI_SMI}	QPI & SMI (PLL BW of 7.8MHz 100/133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.22	0.49	0.5	ps (rms)	1,5
		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.16	0.28	0.3	ps (rms)	1,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.11	0.17	0.2	ps (rms)	1,5
	t _{jphPCleG1}	PCIe Gen 1		1	5	N/A	ps (p-p)	1,2,3
		PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.0	0.0	N/A	ps (rms)	1,2,6
	t _{jphPCleG2}	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.0	0.0	N/A	ps (rms)	1,2,6
	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)		0.0	0.0	N/A	ps (rms)	1,2,4,6
<i>Additive</i> Phase Jitter, Bypass mode		QPI & SMI (PLL BW of 17.04MHz 100/133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.25	0.3	N/A	ps (rms)	1,5,6
	t _{jphQPI_SMI}	QPI & SMI (PLL BW of 7.8MHz 100/133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.10	0.15	N/A	ps (rms)	1,5,6
		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.0	0.0	N/A	ps (rms)	1,5,6
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.0	0.0	N/A	ps (rms)	1,5,6

¹ Applies to all outputs.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ Subject to final ratification by PCI SIG.

⁵ Calculated from Intel-supplied Clock Jitter Tool

⁶ For RMS figures, additive jitter is calculated by solving the following equation: (Additive jitter)² = (total jitter)² - (input jitter)²

Clock Periods–Differential Outputs with Spread Spectrum Disabled

				Measurement Window							
		0	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
S	SC OFF	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
	DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3

Clock Periods–Differential Outputs with Spread Spectrum Enabled

			Measurement Window							
	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC ON	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3

Notes:

¹Guaranteed by design and characterization, not 100% tested in production.

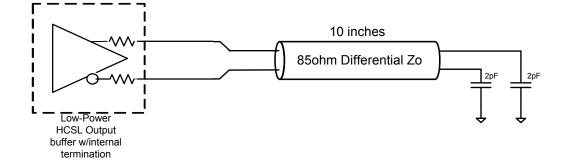
² All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 9ZXL0651 itself does not contribute to ppm error.

³ Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

Test Loads

Differential Output Terminations

DIF Zo (Ω)	Iref (Ω)	Rs (Ω)	Rp (Ω)
100	475	7	50
85	412	0	43.2



General SMBus Serial Interface Information for 9ZXL0651

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Co	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit	_	
-		_	
	lave Address	_	
WR	WRite	_	
			ACK
Beg	jinning Byte = N		
			ACK
RT	Repeat starT		
S	lave Address		
RD	ReaD	-	
			ACK
		-	Data Byte Count=X
	ACK	-	
			Beginning Byte N
	ACK		
		e	0
	0	X Byte	0
	0	×	0
	0	1	
		1	Byte N + X - 1
Ν	Not acknowledge		
Р	stoP bit		

	Index Bl	ock W	/rite Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnir	ig Byte N		
			ACK
0		×	
0		X Byte	0
0		Ō	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

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Byte	Byte 0 Pin # Name		Control Function	Туре	0	1	Default			
Bit 7	2	PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Op	erating Mode	Latch			
Bit 6	2	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readba	ck Table	Latch			
Bit 5		Reserved								
Bit 4			Reserved				0			
Bit 3		PLL_SW_EN	Enable S/W control of PLL BW	RW	HW Latch	SMBus Control	0			
Bit 2		PLL Mode 1	PLL Operating Mode 1	RW	See PLL Op	erating Mode	1			
Bit 1		PLL Mode 0	PLL Operating Mode 1	PLL Operating Mode 1 RW		ck Table	1			
Bit 0			Reserved							

SMBusTable: PLL Mode, and Frequency Select Register

Note: Setting bit 3 to '1' allows the user to overide the Latch value from pin 5 via use of bits 2 and 1. Use the values from the PLL Operating Mode Readback Table. Note that Bits 7 and 6 will keep the value originally latched on pin 5. A warm reset of the system will have to accomplished if the user changes these bits.

SMBusTable: Output Control Register

Byte 1 Pin #		Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				1
Bit 6	26/27	DIF_3_En	Output Control - '0' overrides OE# pin	RW	Low/Low	Enable	1
Bit 5	23/24	DIF_2_En	Output Control - '0' overrides OE# pin	RW	LOW/LOW	Enable	1
Bit 4			Reserved				1
Bit 3			Reserved				1
Bit 2	17/18	DIF_1_En	Output Control - '0' overrides OE# pin	RW		Enable	1
Bit 1	14/15	DIF_0_En	Output Control - '0' overrides OE# pin	RW	Low/Low	Enable	1
Bit 0			Reserved				1

SMBusTable: Output Control Register

Byte 2 Pin #		Pin #	Name	Control Function	Туре	0	1	Default			
Bit 7				Reserved				0			
Bit 6				Reserved							
Bit 5				Reserved							
Bit 4				Reserved				0			
Bit 3				Reserved				1			
Bit 2	3	6/37	DIF_5_En	Output Control - '0' overrides OE# pin	RW		Frable	1			
Bit 1	3	3/34	DIF_4_En	Output Control - '0' overrides OE# pin	RW	Low/Low	Enable	1			
Bit 0				Reserved							

SMBusTable: Reserved Register

Byte	e 3	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				0
Bit 6				Reserved				0
Bit 5				Reserved				0
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0				Reserved				0

SMBusTable: Reserved Register

Byte 4	Pin #	Name	Control Function	Туре	0	1	Default	
Bit 7			Reserved					
Bit 6			Reserved					
Bit 5			Reserved				0	
Bit 4			Reserved				0	
Bit 3		Reserved					0	
Bit 2			Reserved				0	
Bit 1			Reserved				0	
Bit 0			Reserved					

SMBusTable: Vendor & Revision ID Register

Byte 5	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	RID3		R	A rev = 0000		Х
Bit 6	-	RID2	REVISION ID	R			Х
Bit 5	-	RID1	REVISIONID	R			Х
Bit 4	-	RID0		R			Х
Bit 3	-	VID3		R	-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1		R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte 6	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	D	evice ID 7 (MSB)	R			1
Bit 6	-	Device ID 6		R]	1	
Bit 5	-		Device ID 5	R]		1
Bit 4	-	Device ID 4		R	FB Hex		1
Bit 3	-	Device ID 3		R	T D TIEX	nex	1
Bit 2	-		Device ID 2	R			0
Bit 1	-		Device ID 1	R			1
Bit 0	-		Device ID 0	R			1

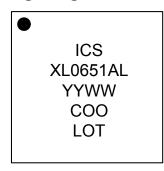
SMBusTable: Byte Count Register

Byte	7 Pin #	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved					
Bit 6		Reserved					0
Bit 5		Reserved					
Bit 4	-	BC4		RW			0
Bit 3	-	BC3	Writing to this register configures how	RW	Default value	is 8 hex, so 9	1
Bit 2	-	BC2	many bytes will be read back.	RW	bytes (0 to 8) w	ill be read back	0
Bit 1	-	BC1	many bytes will be read back.	RW	by de	efault.	0
Bit 0	-	BC0		RW			0

SMBusTable: Reserved Register

Byte	8	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7				Reserved				0
Bit 6				Reserved				0
Bit 5				Reserved				0
Bit 4				Reserved				0
Bit 3				Reserved				0
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0				Reserved				0

Marking Diagram

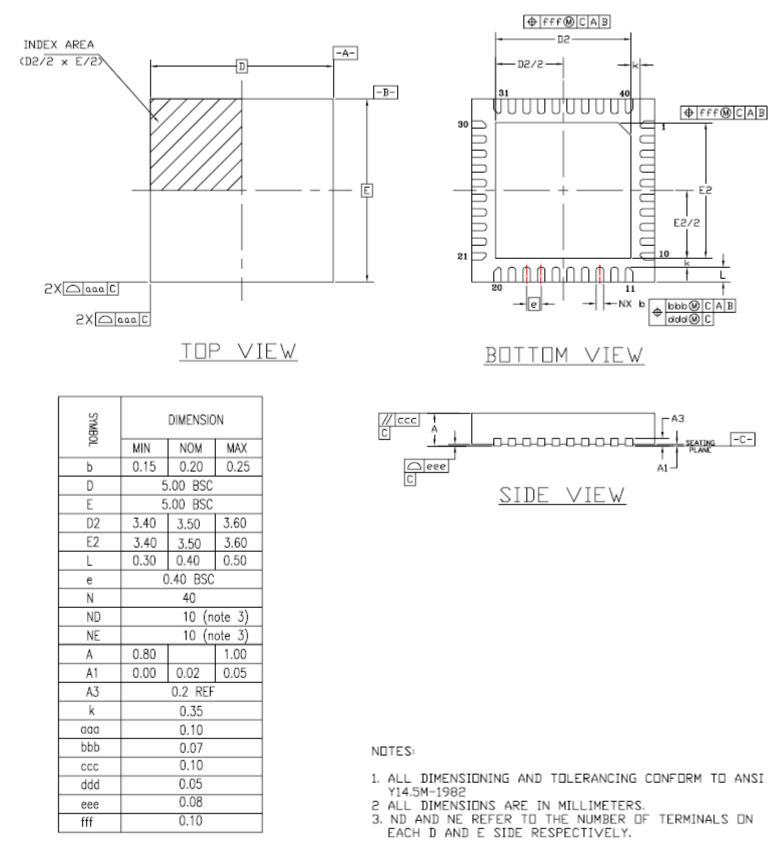


Notes:

- 1. "L" denotes RoHS compliant package.
- 2. 'LOT' denotes the lot number.
- 3. "COO": country of origin.
- 4. YYWW is the last two digits of the year and week that the part was assembled.

Package Outline and Package Dimensions (NDG40)

Package dimensions are kept current with JEDEC Publication No. 95



IDT® 6-OUTPUT LOW-POWER HCSL BUFFER FOR PCIE GEN1-2-3 AND QPI

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9ZXL0651

REV B 112514

Ordering Information

Part / Order Number	rder Number Shipping Package		Temperature	
9ZXL0651AKLF	Trays	40-pin VFQFPN	0 to +70°C	
9ZXL0651AKLFT	Tape and Reel	40-pin VFQFPN	0 to +70°C	

"LF" suffix to the part number denotes Pb-Free configuration, RoHS compliant.

"A" is the device revision designator (will not correlate with the datasheet revision).

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Revision History

Rev.	Issue Date	Issuer	Description	Page #
А	10/31/2013	RDW	Updated Electrical Tables with characterization data and moved to final.	Various
В	11/25/2014		 Updates to Byte 6, bits 7:4; default should be "1". Updated device ID in Byte 6 from "8B" to "FB". 	12

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